

## **KSA1406**

### **CRT Display, Video Output**

- High Current Gain Bandwidth Product : f<sub>T</sub> = 400MHz (Typ.)
- High Collector-Base Breakdown Voltage: V<sub>CBO</sub> = -200V
  Low Reverse Transfer Capacitance: C<sub>re</sub>=1.7pF (Typ.)



## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	- 200	V
V <sub>CEO</sub>	Collector-Emitter Voltage	- 200	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 4	V
I <sub>C</sub>	Collector Current (DC)	- 100	mA
I <sub>CP</sub>	Collector Current (Pulse)	- 200	mA
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1.2	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	7	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -10\mu A, I_B = 0$	- 200			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -1 \text{mA}, R_{BE} = \infty$	- 200			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = -100 \mu A, I_C = 0$	- 4			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = - 150V, I <sub>C</sub> = 0			- 0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = -2V, I_{E} = 0$			- 0.1	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = -10V, I_{C} = -10mA$	40		120	
h <sub>FE2</sub>		$V_{CE} = -10V, I_{C} = -60mA$	20			
V <sub>CE</sub> (Sat)	Collector-Emitter Saturation Voltage	$I_C = -30 \text{mA}, I_C = -3 \text{mA}$			- 0.8	V
V <sub>BE</sub> (Sat)	Base-Emitter Saturation Voltage	$I_C = -30 \text{mA}, I_C = -3 \text{mA}$			- 1.8	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = -30V, I_{C} = -30mA$		400		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = - 30V, f = 1MHz		2.3		pF
C <sub>re</sub>	Reverse Transfer Capacitance	V <sub>CB</sub> = - 30V, f = 1MHz		1.7		pF

## \* h<sub>FE</sub> Classification

Classification	С	D	
h <sub>FE1</sub>	40 ~ 80	60 ~ 120	

# **Typical Characteristics**

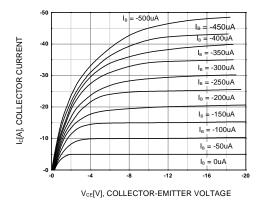


Figure 1. Static Characteristic

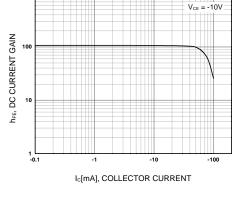


Figure 2. DC current Gain

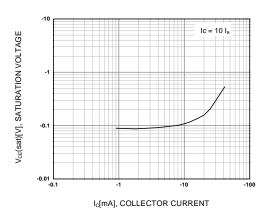


Figure 3. Collector-Emitter Saturation Voltage

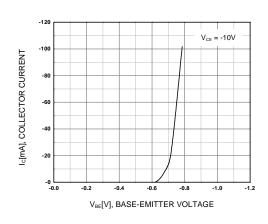


Figure 4. Base-Emitter On Voltage

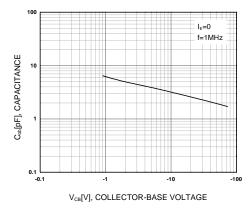


Figure 5. Collector Output Capacitance

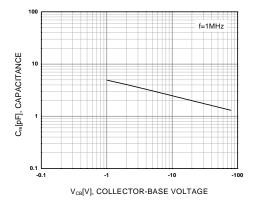


Figure 6. Reverse Capacitance

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# **Typical Characteristics** (Continued)

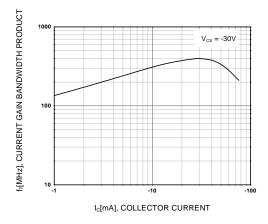


Figure 7. Current Gain Bandwidth Product

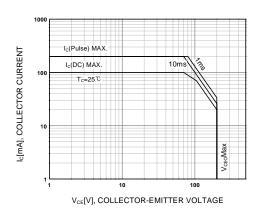


Figure 8. Safe Operating Area

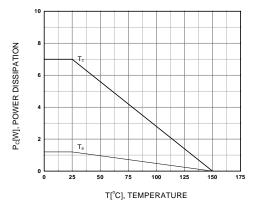
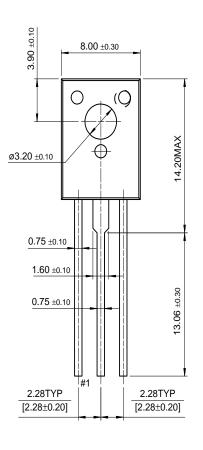


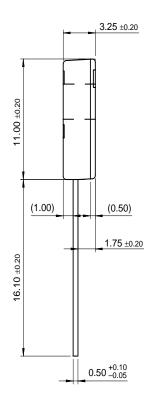
Figure 9. Power Derating

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## **Package Demensions**

TO-126





Dimensions in Millimeters

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